8/16-bit Data Bus Static RAM Card

Connector Type

Two-piece 68-pin

MF365A-J9CATXX MF3129-J9CATXX MF3257-J9CATXX MF3513-J9CATXX MF31M1-J9CATXX MF32M1-J9CATXX MF34M1-J9CATXX

1. DESCRIPTION

Mitsubishi's Static RAM cards provide large memory capacities on a device approximately the size of a credit card (85.6mm×54mm×3.3mm). The cards use a 8/16 bit data-bus.

Available in 64KB, 128KB, 256KB, 512KB, 1 MB, 2 MB and 4 MB capacities, Mitsubishi's SRAM cards conform to the PC Card Standard. Mitsubishi achieved high density memory, while maintaining credit size by using a thin small outline packaging technology (TSOP). The TSOP surpasses conventional memory card chip-on-board packaging technology where larger, surface-mount devices result in a tradeoff between card size and optimum memory density. The TSOP, with external leads spaced on 20-mil centers, is over four times smaller than standard equivalent pin count surface-mount packages. This allows up to 8 memory ICs (plus interface circuitry) to be mounted in a card that in only 3.3mm thick.

2. FEATURES

- ■Uses TSOP (Thin Small Outline Package) to achieve very high memory density coupled with high reliability, without enlarging card size
- Electrostatic discharge protection to 15kV
- ■Buffered interface
- ■Write protect switch
- ■68pin
- ■Built-in auxiliary battery

3. APPLICATIONS

- ■Office automation
- ■Computers
- Telecommunications
- ■Data Communication ■Industrial
 - ■Consumer

4.	PR	OD	UCT	LIST
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Item	Memory	Data Bus	Attribute	Auxiliary
Type name	capacity	width(bits)	memory	battery
MF365A-J9CATXX	64KB			
MF3129-J9CATXX	128KB			
MF3257-J9CATXX	256KB			
MF3513-J9CATXX	512KB	8/16	NO	YES
MF31M1-J9CATXX	1MB			
MF32M1-J9CATXX	2MB			
MF34M1-J9CATXX	4MB			



5. SUMMARY

MF3XXX-J9CATXX series is the Static RAM cards which has 8/16 bit changeable data-bus width. The card has a replaceable lithium main battery to maintain data in memory and has an auxiliary battery to maintain data in memory while the main battery is replaced. When the card is not use or the supply voltage drops, the main battery will automatically maintain data in memory.

6. FUNCTIONAL DESCRIPTION

The function of the card is determined by the combination of the following five control signals, REG#, CE1#, CE2#, OE#, WE#; active low signals. (Please refer to section 10 FUNCTION TABLE on page 5) (1)COMMON MEMORY FUNCTION

When REG# signal is high level, the common memory area is selected.

(a)READ MODE

To read, WE# is set high level and CE1# or CE2# is set low level and the memory address is applied at inputs A0-A21(4MB). Setting OE# low level executes the reading with output at data-bus. It is available to make the following functions according to the combination of CE1# and CE2#.

When CE1# is set low level and CE2# is set high level, the card operates as an 8 bit data-bus width card. The data can be dealt with lower data-bus(D0-D7).

When both CE1# and CE2# are set low level, the card operates as a 16 bit data-bus width card. At this mode LSB of address-bus (A0) is ignored.

In addition odd byte can be accessed through upper data-bus(D8-D15) when CE1# is set high level and CE2# is set low level. This mode is useful when handling only odd bytes in the 16 bit data-bus interface system (A0 is ignored).

When both CE1# and CE2# are set high level, the card becomes a standby mode where the card consumes low power and the data-bus is placed in high impedance state (above functions of CE1# and CE2# are the same as in the following modes).

When both OE# and WE# are set high level, the card becomes a output disable mode and the data-bus is placed in high impedance state.

(b)WRITE MODE

To write, the memory address is first applied at inputs A0-A21(4MB) and the data is applied at output pins. Setting CE1# or CE2# low level, WE# low level and OE# high level executes the writing.

(2)ATTRIBUTE MEMORY FUNCTION

When REG# is set low level, the attribute memory area is selected. MF3XXX-J9CATXX series have no attribute memory but outputs FFh on the lower data-bus(D0-D7) when the following conditions are applied (a)setting CE1# low, CE2# high, OE# low, WE# high and A0 low

(b)setting CE1# low, CE2# low, OE# low and WE# high

(3)BATTERY

When the card is used for long periods of time, eventually battery exhaustion occurs. If such a situation is encountered, replace any exhausted battery with a new one as directed in section 21.2 "REPLACING BATTERY" (page 14).

The replacement battery model number is indicated under section 21 "BATTERY SPECIFICATIONS" (page 14).

7. WRITE PROTECT MODE

When the write protect switch is switched on, this card goes into a write protect mode that can read but not write data. In this mode, WP pin becomes "H" level.

At the shipment the write protect switch is switched off (Normal mode : The card can be written ; WP pin indicates "L" level).



Pin	Symbol	Eunction	Pin	Symbol	Function
No.	Symbol	i unetron	No.	~,	
1	GND	Ground	35	GND	Ground
2	D3)	36	CD1#	Card detect 1
3	D4		37	D11	h
4	D5	> Data I/O	38	D12	
5	D6		39	D13	> Data I/O
6	D7)	40	D14	
7	CE1#	Card enable 1	41	D15)
8	A10	Address input	42	CE2#	Card enable 2
9	OE#	Output enable	43	NC	
10	A11)	44	NC	> No connection
11	A9		45	NC)
12	A8	> Address input	46	A17	A17 (NC for < 128 KB types))
13	A13	-	47	A18	A18 (NC for < 256 KB types)
14	A14)	48	A19	A19 (NC for $<$ 512KB types) Address
15	WE#	Write enable	49	A20	A20 (NC for < 1 MB type) input
16	NC	No connection	50	A21	A21 (NC for $< 2MB$ type)
17	VCC	Power supply voltage	51	VCC	Power supply voltage
18	NC	No connection	52	NC	
19	A16	A16 (NC for 64KB type)	53	NC	
20	A15		54	NC	
21	A12		55	NC	
22	A7		56	NC	> No connection
23	A6		57	NC	
24	A5	Address input	58	NC	
25	A4		59	NC	
26	A3		60	NC	γ
27	A2		61	REG#	Attribute memory select
28	A1		62	BVD2	Battery voltage detect 2
29	A0	J	63	BVD1	Battery voltage detect 1
30	D0)	64	D8	
31	D1	Data I/O	65	D9	Data I/O
32	D2	J	66	D10	IJ
33	WP	Write protect	67	CD2#	Card detect 2
34	GND	Ground	68	GND	Ground

8. PIN ASSIGNMENTS



9. BLOCK DIAGRAM (4MB) (MF34M1-J9CATXX)





10. FUNCTION TABLE

Mode	REG#	CE1#	CE2#	OE#	WE#	A0	I/O (D15~D8)	I/O (D7~D0)	Icc
Standby	Х	Н	Н	Х	Х	Х	High-impedance	High-impedance	standby
Read A (16bit)	Н	L	L	L	Н	Х	Odd Byte	Even Byte	Active
common							Data out	Data out	
Write A (16bit)	Н	L	L	Н	L	Х	Odd Byte	Even Byte	Active
common							Data in	Data in	
Read B (8bit)	Н	L	Н	L	Н	L	High-impedance	Even Byte	Active
common								Data out	
	Н	L	Н	L	Н	Η	High-impedance	Odd Byte	Active
								Data out	
Write B (8bit)	Н	L	Н	Н	L	L	High-impedance	Even Byte Data in	Active
common	Н	L	Н	Н	L	Н	High-impedance	Odd Byte Data in	Active
Read C (8bit)	Н	Н	L	L	Н	Х	Odd Byte	High-impedance	Active
common							Data out		
Write C (8bit)	Н	Н	L	Н	L	Х	Odd Byte	High-impedance	Active
common							Data in		
Output disable	Х	Х	Х	Н	Н	Х	High-impedance	High-impedance	Active
Read A (16bit)	L	L	L	L	Н	Х	Data out	Data out	Active
attribute							(unknown)	(FFh)	
Read B (8bit)	L	L	Н	L	Н	L	High-impedance	Data out	Active
attribute								(FFh)	
	L	L	Н	L	Н	Н	High-impedance	Data out	Active
								(unknown)	
Read C (8bit)	L	Н	L	L	Н	Х	Data out	High-impedance	Active
attribute							(unknown)		

Note 1 : H=VIH, L=VIL, X=VIH or VIL

11. ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
Vcc	Supply voltage		-0.3~6.0	V
VI	Input voltage	With respect to GND	-0.3~VCC+0.3	V
Vo	Output voltage		0~VCC	V
Topr1	Operating temperature 1	Read, Write Operation	0~60	°C
Topr2	Operating temperature 2	Data retention	0~60	°C
Tstg	Storage temperature	Excludes data retention	-20~70	°C

12. RECOMMENDED OPERATING CONDITIONS (Ta=0~55°C, unless otherwise noted)

Symbol	Darameter		Unit		
	i arameter	Min.	Тур.	Max.	Omt
Vcc	Vcc Supply voltage	4.75	5.0	5.25	V
GND	System ground		0		V
Vih	High input voltage	2.4		VCC	V
VIL	Low input voltage	0		0.8	V



Symbol	Parameter		Test conditions	,		Limits		Unit
						Тур.	Max.	
Voh	High output voltage	Iон= -1.0mA			2.4			V
Vol	Low output voltage	IOL=2mA					0.4	V
Iih	High input current	VI=Vcc V					10	μΑ
IIL	Low input current	VI=0V	CE1#, CE2#, W	E#, OE#, REG#	-10		-70	μΑ
			Other inputs				-10	
Iozh	High output current	CE1#=CE2#=`	VIH or OE#=VIH V	WE#=Vih,			10	μΑ
	in off state	Vo=Vcc						
Iozl	Low output current	CE1#=CE2#=`	VIH or OE#=VIH V	WE#=Vih,			-10	μA
	in off state	Vo=0V						
Icc 1 • 1	Active supply	CE1#=CE2#=`	VIL, other inputs	64KB~512KB			170	mA
	current 1	=VIH or VIL,O	utputs=open	1MB~4MB			230	
Icc 1 • 2	Active supply	CE1#=CE2# ≤	0.2V, other	64KB~512KB			160	mA
	current 2	inputs $\leq 0.2 V$	or					
		\geq Vcc-0.2V, O	utputs=open	1MB~4MB			220	
Icc 2 • 1	Standby supply	CE1#=CE2#=`	Vih	64KB~4MB			10	mA
	current 1	other inputs=V	IH or VIL				(17)	
Icc 2 • 2	Standby supply	CE1#=CE2# ≥	: Vcc-0.2V	64KB~512KB			0.45	mA
	current 2	other inputs \leq	0.2V or				(7.45)	
		\geq Vcc-0.2V		1MB~4MB			0.65	
							(7.65)	
VBDET1	Battery detect	Vcc=5V, Ta=2	25°C		2.27	2.37	2.47	V
	reference voltage							
VBDET2	Battery detect	Vcc=5V, Ta=2	25°C		2.55	2.65	2.75	V
	reference voltage							1

13. ELECTRICAL CHARACTERISTICS (Ta=0~55°C, Vcc=5V±5%, unless otherwise noted)

Note 2 : Currents flowing into the card are taken as positive (unsigned).

3 : Typical values are measured at Vcc=5V, Ta= 25° C.

4 : The figure in the parentheses indicates the standby current limits when the built-in auxiliary battery is not fully charged.

14. CAPACITANCE

Symbol	Decomptor Test conditions	Test conditions		TL		
Symbol	Falameter	Test conditions	Min.	Тур.	Max.	Unit
Сі	Input capacitance	VI=GND, vi=25mVrms				
		f=1MHz, Ta=25°C			30	pF
Со	Output Capacitance	Vo=GND, vo=25mVrms f=1MHz, Ta=25°C			20	pF

Note 4 : These parameters are not 100% tested.



15. SWITCHING CHARACTERISTICS

Read Cycle (Ta=0~55°C, VCC=5V±5%, unless otherwise noted)

Symbol	Parameter	Lim	its	Unit
		Min.	Max.	
tcR	Read cycle time	150		ns
ta(A)	Address access time		150	ns
ta(CE)	Card enable access time		150	ns
ta(OE)	Output enable access time		75	ns
tdis(CE)	Output disable time (from CE#)		75	ns
tdis(OE)	Output disable time (from OE#)		75	ns
ten(CE)	Output enable time (from CE#)	5		ns
ten(OE)	Output enable time (from OE#)	5		ns
tv(A)	Data valid time (after address change)	0		ns

16. TIMING REQUIREMENTS

Write Cycle (Ta=0~55°C, Vcc=5V±5%, unless otherwise noted)

Symbol	Parameter	Lin	nits	Unit
		Min.	Max.	
tcW	Write cycle time	150		ns
tw(WE)	Write pulse width	80		ns
tsu(A)	Address set up time	20		ns
tsu(A-WEH)	Address set up time with respect to WE# high	100		ns
tsu(CE-WEH)	Card enable set up time with respect to WE# high	100		ns
t(D-WEH)	Data set up time with respect to WE# high	50		ns
th(D)	Data hold time	20		ns
trec(WE)	Write recovery time	20		ns
tdis(WE)	Output disable time (from WE#)		75	ns
tdis(OE)	Output disable time (from OE#)		75	ns
ten(WE)	Output enable time (from WE#)	5		ns
ten(OE)	Output enable time (from OE#)	5		ns
tsu(OE-WE)	OE# set up time with respect to WE# low	10		ns
th(OE-WE)	OE# hold time with respect to WE# high	10		ns





WE#="H" level REG#="H" level



REG#="H" level





OE#="H" level REG#="H" level

Write Cycle (CE# control)

17. SWITCHING CHARACTERISTICS (Attribute)

Read Cycle (Ta=0~55°C, Vcc=5V±5%, unless otherwise noted)

Symbol	Parameter	Lin	Limits	
		Min.	Max.	
tcRR	Read cycle time	300		ns
ta(A)R	Address access time		300	ns
ta(CE)R	Card enable access time		300	ns
ta(OE)R	Output enable access time		150	ns
tdis(CE)R	Output disable time (from CE#)		100	ns
tdis(OE)R	Output disable time (from OE#)		100	ns
ten(CE)R	Output enable time (from CE#)	5		ns
ten(OE)R	Output enable time (from OE#)	5		ns
tV(A)R	Data valid time after address change	0		ns







Symbol Parameter Test conditions Limits Unit Min. Тур. Max. VBATT Back-up enable battery voltage 2.6 All pins open V Vi(CE) Card enable voltage 2.4V≤VCC≤5.25V 2.4 V 0V≤VCC<2.4V Vcc-0.1 Vcc Vcc+0.1 64KB 3 128KB 3 All pins open, 3 256KB VBATT=3V, Battery back-up supply current 512KB 5 μΑ Ta=25°C 1MB 3 2MB 5 Icc 4MB 9 64KB 30 (Bup) 30 128KB All pins open, 256KB 30 VBATT=3V Battery back-up supply current 512KB 50 μA 1MB 30 2MB 50 4MB 90

18. ELECTRICAL CHARACTERISTICS

BATTERY BACKUP (Ta=0~55°C, unless otherwise noted)

19. TIMING REQUIREMENTS (Ta=0~55°C, unless otherwise noted)

Symbol	Parameter		Limits		Unit
		Min.	Тур.	Max.	
Tpr	Power supply rise time	0.1		300	ms
tpf	Power supply fall time	3		300	ms
tsu(Vcc)	Setup time at power on	20			ms
trec(Vcc)	Recovery time at power off	1000			ns

CARD INSERTION/REMOVAL TIMING DIAGRAM



20. BATTERY SPECIFICATIONS

Please use the following coin type lithium battery.

Type of main battery; CR2025 or equivalents

20.1 BATTERY LIFE EXPECTANCY

The calculated main battery's life expectancies are as follows.

Card Type	main battery's life
	(when the card is left continuously)
MF365A-J9CATXX	5.9years
MF3129-J9CATXX	5.9years
MF3257-J9CATXX	5.9years
MF3513-J9CATXX	3.6years
MF31M1-J9CATXX	5.9years
MF32M1-J9CATXX	3.6years
MF34M1-J9CATXX	2.0years

Conditions; Temperature : 25°C Humidity : 60%RH



CE2#

20.2 REPLACING BATTERY

- MF3XXX-J9CATXX series have two batteries inside the card as follows.
 - Lithium battery; for main battery (replaceable)

Rechargeable battery; for auxiliary battery (not replaceable)

For main battery replacement, perform the following procedure. Performing any other procedures will lose the data recorded in the IC card.

(1)Have on hand a new main battery that has the same model number as or is equivalent currently installed one.

- (2)Insert the IC card into the system and apply power to the IC card so that the auxiliary battery will be charged. (more than 5 minutes)
- (3)While pressing the main battery holder cam release levers inward, slowly withdraw the main battery holder.
- (4)With the new main battery set in the battery holder, insert it completely into the IC card.
- (5)If the battery holder is incorrectly oriented, it will not smoothly fit into its position or the IC card will bulge. If such a situation is encountered, properly reorient the battery and battery holder and try again.

(6)Insert the battery holder until it clicks into position.

<NOTICE>

Main battery replacement must be completed quickly (recommended time is within 10 minutes).

If too much time is taken, the recorded data may be lost.

The built-in auxiliary battery cannot be replaced.

21. CONNECTOR

The number of card insertion and removal are as follows.

Office environment	10000 times min. at speed of 10 cycles/min.
Harsh environment	5000 times min. at speed of 10 cycles/min.

22. CARD WEIGHT about 35g

23. UL CLASS OF MAIN CARD PARTS

(1)MAIN FRAME	UL94V-0
(2)PCB	UL94V-0
(3)PLASTIC PART OF CONNECTOR	UL94V-0

24. THE BATTERY VOLTAGE DETECT SIGNALS (BVD1,2)

BVD1	BVD2	Comment
Н	Н	Battery operational
Н	L	Battery operational, but battery should be replaced
L	L	Battery and data integrity is not kept

Note10. The battery voltage detect signals indicate the present state of the battery. They do not guarantee the data retention.

25.CONCERNING THE SECURITY OF DATA

There is always the possibility that a soft-error (this malfunction is not permanent hence it is called soft and the data can be restored by rewriting) may occur with semiconductor products.

When keeping the important data within an IC card, remember to give due consideration to safety when making your circuit designs, with appropriate measures such as

- (1) Keeping multiple copies of the data.
- (2) Addition of ECC or CRC by software or hardware.



– \triangle Warning (if card with battery / card with auxiliary battery) –

(1)Do not charge, short, disassemble, deform, heat, or throw the batteries into fire, as they may ignite, overheat, rupture or explode.

- (2)Place the batteries out of the reach of children. If somebody swallows them, they should see a doctor immediately.
- (3)When discarding or storing the batteries, wrap them individually with cellophane tape or other nonconductive material. If they are positioned in contact with any other metals or batteries, they may explode, rupture or leak electrolyte solution.

- 🕂 Caution

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OUTLINE(68P-012)



